

# **DTB123Y**

# PNP SILICON TRANSISTOR

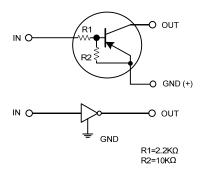
# DIGITAL TRANSISTORS (BUILT- IN BIAS RESISTORS)

# FEATURES

\* Built-in bias resistors that implies easy ON/OFF applications.

\* The bias resistors are thin-film resistors with complete isolation to allow positive input.

### EQUIVALENT CIRCUIT



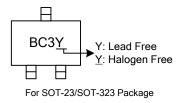
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### ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignment			Decking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
DTB123YL-AE3-R	DTB123YG-AE3-R	SOT-23	G	I	0	Tape Reel	
DTB123YL-AL3-R	DTB123YG-AL3-R	SOT-323	G	I	0	Tape Reel	
DTB123YL-T92-K	DTB123YG-T92-K	TO-92	G	0	I	Bluk	
DTB123YL-T92-B	DTB123YG-T92-B	TO-92	G	0	I	Tape Box	

DTB123YL- <u>AE3-R</u>	(1)Packing Type	(1) B: Tape Box, K: Bluk, R: Tape Reel
	(2)Package Type (3)Lead Free	(2) AE3: SOT-23, AL3: SOT-323, T92: TO-92 (3) G:Halogen Free, L: Lead Free

# MARKING



### ■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER			RATINGS	UNIT	
Supply Voltage		V <sub>CC</sub>	-50	V	
Input Voltage		V <sub>IN</sub> -12 ~ +5		V	
Output Current		Ι <sub>C</sub>	-500	mA	
Dower Dissinction	SOT-23/ SOT-323	Б	200	mW	
Power Dissipation	TO-92	PD	625	mW	
Junction Temperature		TJ	+150	°C	
Storage Temperature		T <sub>STG</sub>	-55 ~ +150	°C	

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

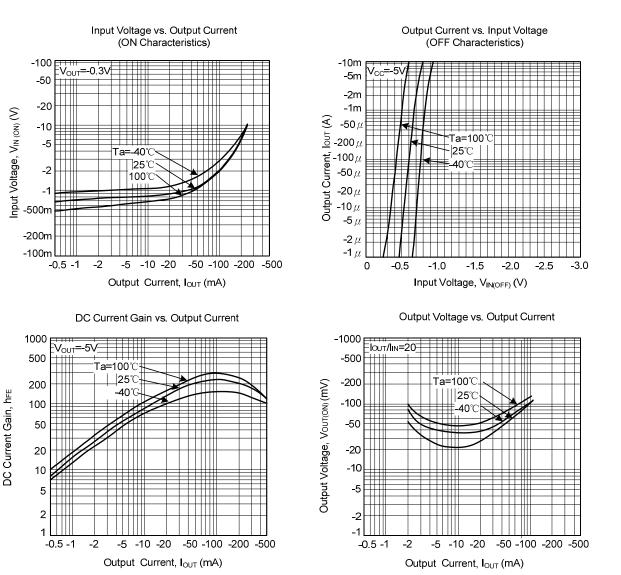
### ■ ELECTRICAL SPECIFICATIONS (Ta=25°C, unless others specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	V <sub>IN(OFF)</sub>	V <sub>CC</sub> =-5V, I <sub>OUT</sub> =-100µA			-0.3	v
	VIN(ON)	V <sub>OUT</sub> =-0.3V, I <sub>OUT</sub> =-20mA	-2			v
Output Voltage	V <sub>OUT(ON)</sub>	I <sub>OUT</sub> /I <sub>IN</sub> =-50mA/-2.5mA		-0.1	-0.3	V
Input Current	I <sub>IN</sub>	V <sub>IN</sub> =-5V			-3.0	mA
Output Current	I <sub>OUT(OFF)</sub>	V <sub>CC</sub> =-50V, V <sub>IN</sub> =0V			-0.5	μA
DC Current Gain	h <sub>FE</sub>	V <sub>OUT</sub> =-5V, I <sub>OUT</sub> =-50mA	56			
Input Resistance	R₁		1.54	2.2	2.86	KΩ
Resistor Ratio	$R_2/R_1$		3.6	4.5	5.5	
Transition Frequency (Note)	f⊤	V <sub>CE</sub> =-10V, I <sub>E</sub> =50mA, f=100MHz		200		MHz

Note: Transition frequency of the device



# TYPICAL CHARACTERISTICS



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